



TN12, TS12 and TYNx12 Series

SENSITIVE & STANDARD

12A SCRs

Table 1: Main Features

Symbol	Value	Unit
$I_{T(RMS)}$	12	A
V_{DRM}/V_{RRM}	600 to 1000	V
I_{GT}	0.2 to 15	mA

DESCRIPTION

Available either in sensitive (**TS12**) or standard (**TN12 / TYN**) gate triggering levels, the 12A SCR series is suitable to fit all modes of control, found in applications such as overvoltage crowbar protection, motor control circuits in power tools and kitchen aids, inrush current limiting circuits, capacitive discharge ignition and voltage regulation circuits...

Available in through-hole or surface-mount packages, they provide an optimized performance in a limited space area.

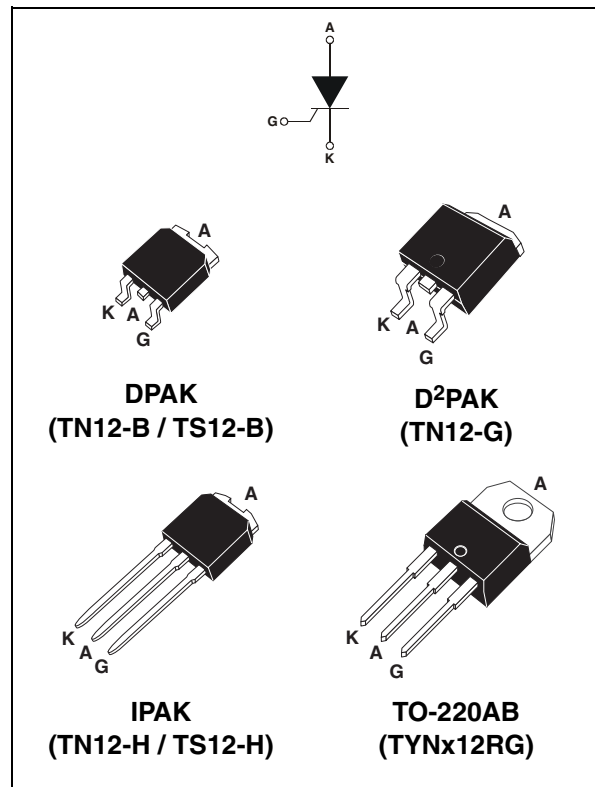


Table 2: Order Codes

Part Numbers	Marking
TN1215-x00B	TN1215x00
TN1215-x00B-TR	TN1215x00
TN1215-x00G	TN1215x00G
TN1215-x00G-TR	TN1215x00G
TN1215-x00H	TN1215x00
TS1220-x00B	TS1220x00
TS1220-x00B-TR	TS1220x00
TS1220-x00H	TS1220x00
TYNx12RG	TYNx12
TYNx12TRG	TYNx12T

TN12, TS12 and TYNx12 Series

Table 3: Absolute Ratings (limiting values)

Symbol	Parameter		Value		Unit	
			TN12-G TYN12	TN12-B/H TS12-B/H		
$I_{T(RMS)}$	RMS on-state current (180° conduction angle)	$T_c = 105^\circ\text{C}$	12		A	
$I_{T(AV)}$	Average on-state current (180° conduction angle)	$T_c = 105^\circ\text{C}$	8		A	
I_{TSM}	Non repetitive surge peak on-state current	$t_p = 8.3\text{ ms}$	$T_j = 25^\circ\text{C}$	145	115	A
		$t_p = 10\text{ ms}$		140	110	
I^2t	I^2t Value for fusing	$t_p = 10\text{ ms}$	$T_j = 25^\circ\text{C}$	98	60	A^2s
di/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$, $t_r \leq 100\text{ ns}$	$F = 60\text{ Hz}$	$T_j = 125^\circ\text{C}$	50		$\text{A}/\mu\text{s}$
I_{GM}	Peak gate current	$t_p = 20\text{ }\mu\text{s}$	$T_j = 125^\circ\text{C}$	4		A
$P_{G(AV)}$	Average gate power dissipation		$T_j = 125^\circ\text{C}$	1		W
T_{stg} T_j	Storage junction temperature range Operating junction temperature range			- 40 to + 150 - 40 to + 125		$^\circ\text{C}$
V_{RGM}	Maximum peak reverse gate voltage (for TN12 & TYN12 only)			5		V

Tables 4: Electrical Characteristics ($T_j = 25^\circ\text{C}$, unless otherwise specified)

■ SENSITIVE

Symbol	Test Conditions			TS1220	Unit	
I_{GT}	$V_D = 12\text{ V}$ $R_L = 140\text{ }\Omega$		MAX.	200	μA	
V_{GT}			MAX.	0.8	V	
V_{GD}	$V_D = V_{DRM}$ $R_L = 3.3\text{ k}\Omega$ $R_{GK} = 1\text{ k}\Omega$	$T_j = 125^\circ\text{C}$	MIN.	0.1	V	
V_{RG}	$I_{RG} = 10\text{ }\mu\text{A}$		MIN.	8	V	
I_H	$I_T = 50\text{ mA}$ $R_{GK} = 1\text{ k}\Omega$		MAX.	5	mA	
I_L	$I_G = 1\text{ mA}$ $R_{GK} = 1\text{ k}\Omega$		MAX.	6	mA	
dV/dt	$V_D = 65\% V_{DRM}$ $R_{GK} = 220\text{ }\Omega$	$T_j = 125^\circ\text{C}$	MIN.	5	$\text{V}/\mu\text{s}$	
V_{TM}	$I_{TM} = 24\text{ A}$ $t_p = 380\text{ }\mu\text{s}$	$T_j = 25^\circ\text{C}$	MAX.	1.6	V	
V_{T0}	Threshold voltage		$T_j = 125^\circ\text{C}$	MAX.	0.85	V
R_d	Dynamic resistance		$T_j = 125^\circ\text{C}$	MAX.	30	$\text{m}\Omega$
I_{DRM} I_{RRM}	$V_{DRM} = V_{RRM}$ $R_{GK} = 220\text{ }\Omega$	$T_j = 25^\circ\text{C}$	MAX.	5	μA	
		$T_j = 125^\circ\text{C}$		2	mA	

■ STANDARD

Symbol	Test Conditions		TN1215		TYN		Unit		
			B / H	G	x12T	x12			
I_{GT}	$V_D = 12\text{ V}$	$R_L = 33\ \Omega$	MIN.	2	0.5	2	mA		
			MAX.	15	5	15			
V_{GT}			MAX.	1.3			V		
V_{GD}	$V_D = V_{DRM}$	$R_L = 3.3\text{ k}\Omega$	$T_j = 125^\circ\text{C}$	MIN.	0.2		V		
I_H	$I_T = 500\text{ mA}$	Gate open		MAX.	40	30	15	30	mA
I_L	$I_G = 1.2 I_{GT}$			MAX.	80	60	30	60	mA
dV/dt	$V_D = 67\% V_{DRM}$	Gate open		$T_j = 125^\circ\text{C}$	MIN.	200	40	200	V/ μs
V_{TM}	$I_{TM} = 24\text{ A}$	$t_p = 380\ \mu\text{s}$	$T_j = 25^\circ\text{C}$	MAX.	1.6				V
V_{t0}	Threshold voltage		$T_j = 125^\circ\text{C}$	MAX.	0.85				V
R_d	Dynamic resistance		$T_j = 125^\circ\text{C}$	MAX.	30				m Ω
I_{DRM} I_{RRM}	$V_{DRM} = V_{RRM}$		$T_j = 25^\circ\text{C}$	MAX.	5				μA
			$T_j = 125^\circ\text{C}$		2				mA

Table 6: Thermal resistance

Symbol	Parameter		Value	Unit	
$R_{th(j-c)}$	Junction to case (DC)		1.3	$^\circ\text{C/W}$	
$R_{th(j-a)}$	Junction to ambient (DC)	$S = 0.5\text{ cm}^2$	DPAK	70	$^\circ\text{C/W}$
		$S = 1\text{ cm}^2$	D ² PAK	45	
			IPAK	100	
			TO-220AB	60	

S = Copper surface under tab.

Figure 1: Maximum average power dissipation versus average on-state current

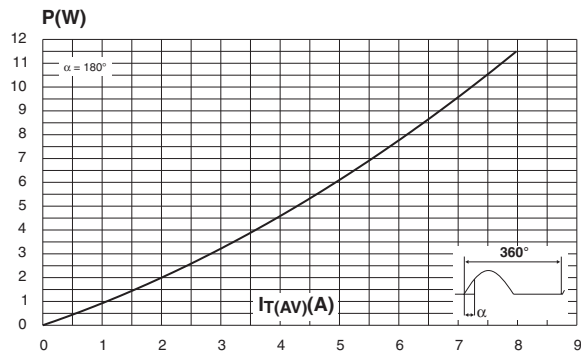


Figure 2: Average and D.C. on-state current versus case temperature

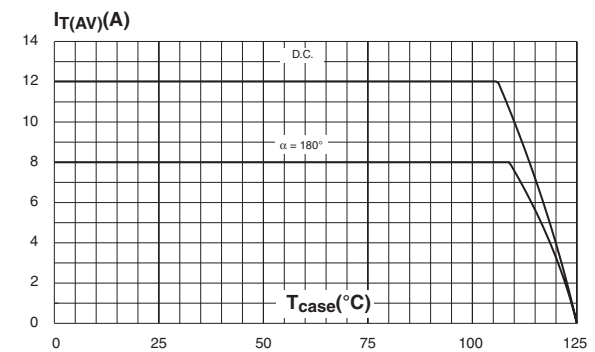


Figure 3: Average and D.C. on-state current versus ambient temperature (device mounted on FR4 with recommended pad layout) (DPAK)

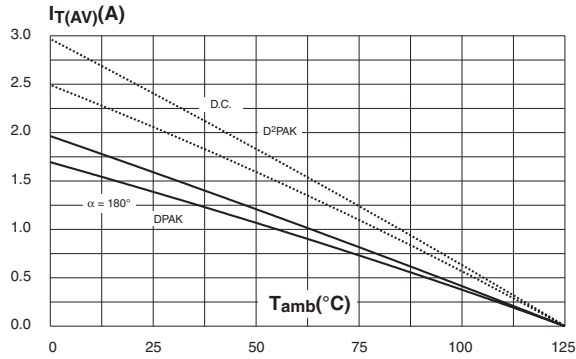


Figure 4: Relative variation of thermal impedance junction to case versus pulse duration

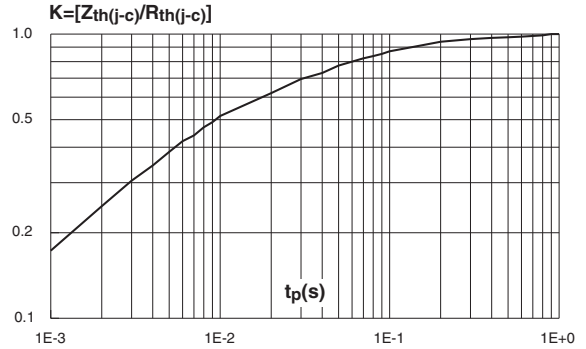


Figure 5: Relative variation of thermal impedance junction to ambient versus pulse duration (recommended pad layout, FR4 PC board for DPAK)

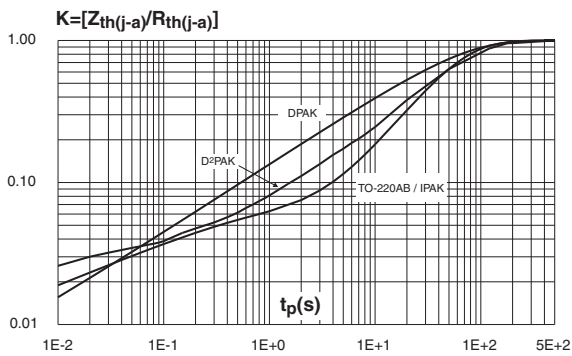


Figure 6: Relative variation of gate trigger current and holding current versus junction temperature for TS8 series

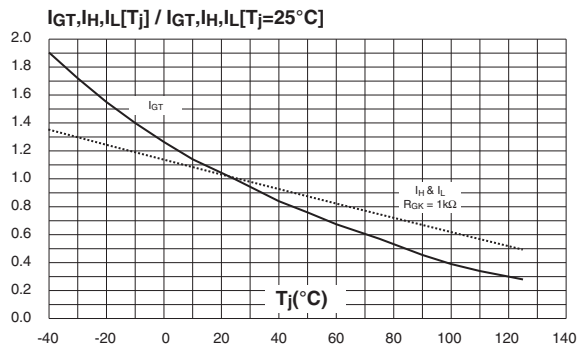


Figure 7: Relative variation of gate trigger current and holding current versus junction temperature for TN8 & TYN08 series

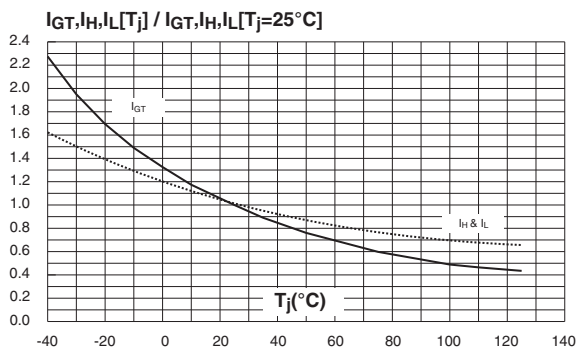


Figure 8: Relative variation of holding current versus gate-cathode resistance (typical values) for TS8 series

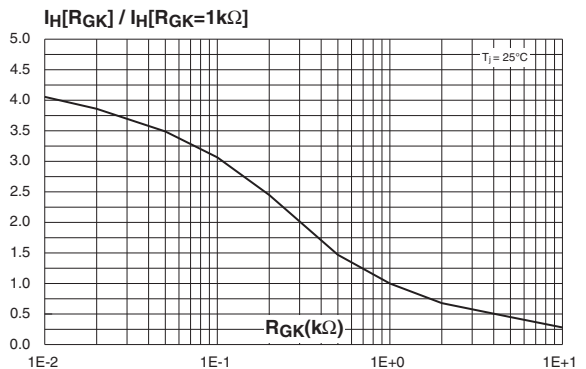


Figure 9: Relative variation of dV/dt immunity versus gate-cathode resistance (typical values) for TS8 series

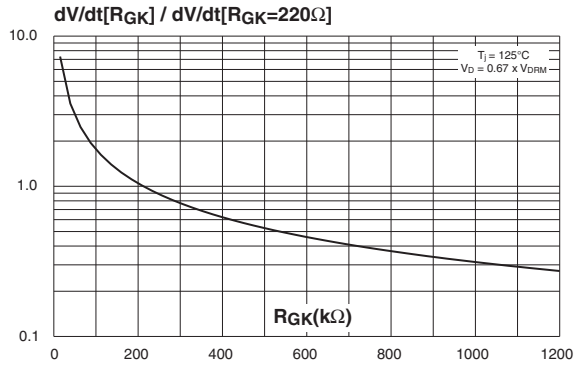


Figure 10: Relative variation of dV/dt immunity versus gate-cathode capacitance (typical values) for TS8 series

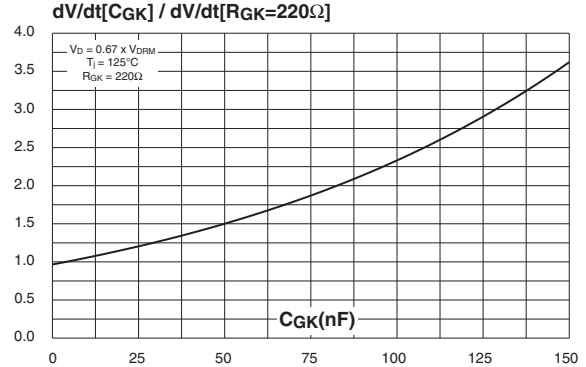


Figure 11: Surge peak on-state current versus number of cycles

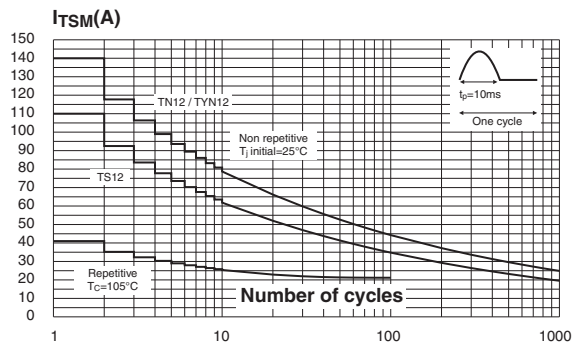


Figure 12: Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 10\text{ ms}$, and corresponding values of I^2t

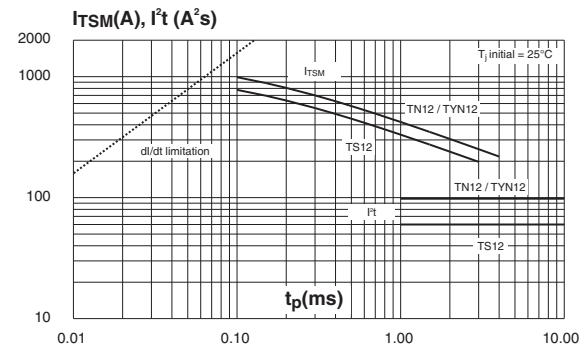


Figure 13: On-state characteristics (maximum values)

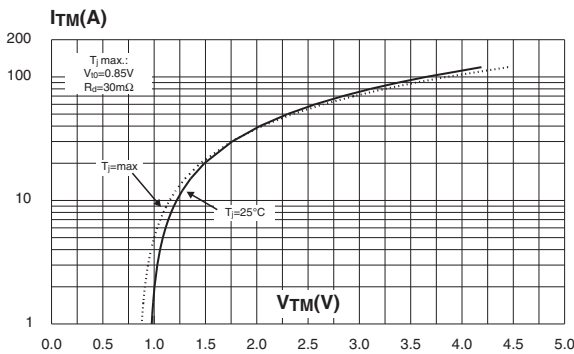
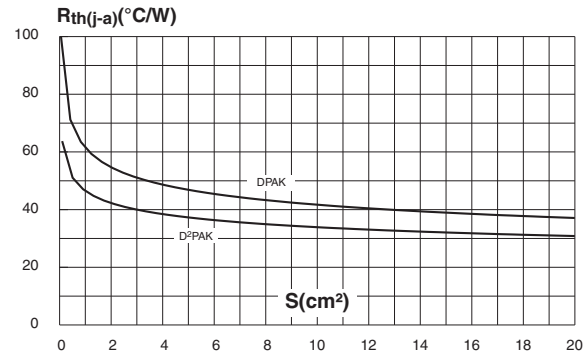


Figure 14: Thermal resistance junction to ambient versus copper surface under tab (epoxy printed circuit board FR4, copper thickness: 35µm) (DPAK and D²PAK)



TN12, TS12 and TYNx12 Series

Figure 15: Ordering Information Scheme (TN8 series)

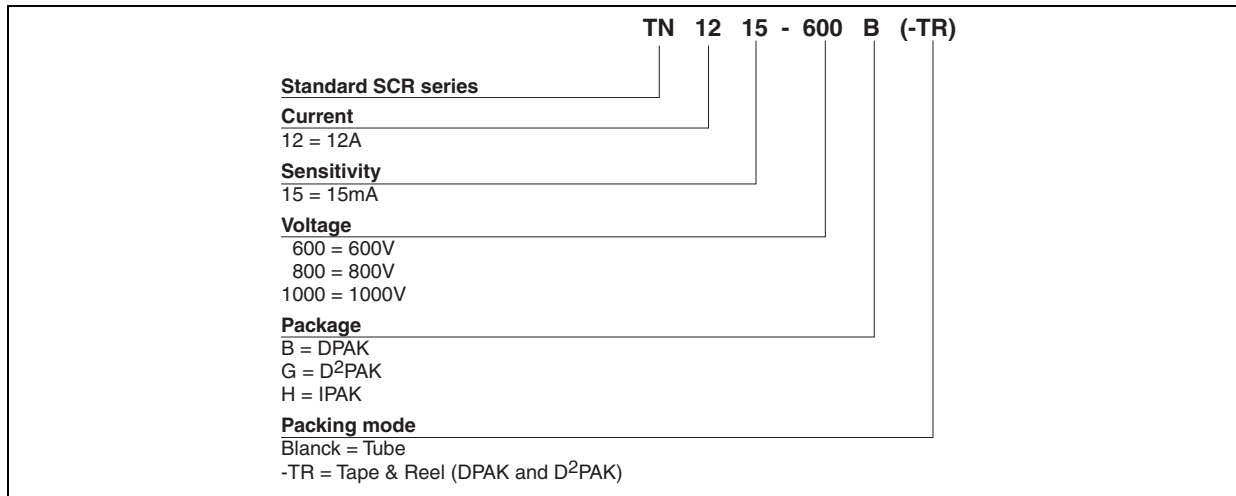


Figure 16: Ordering Information Scheme (TS8 series)

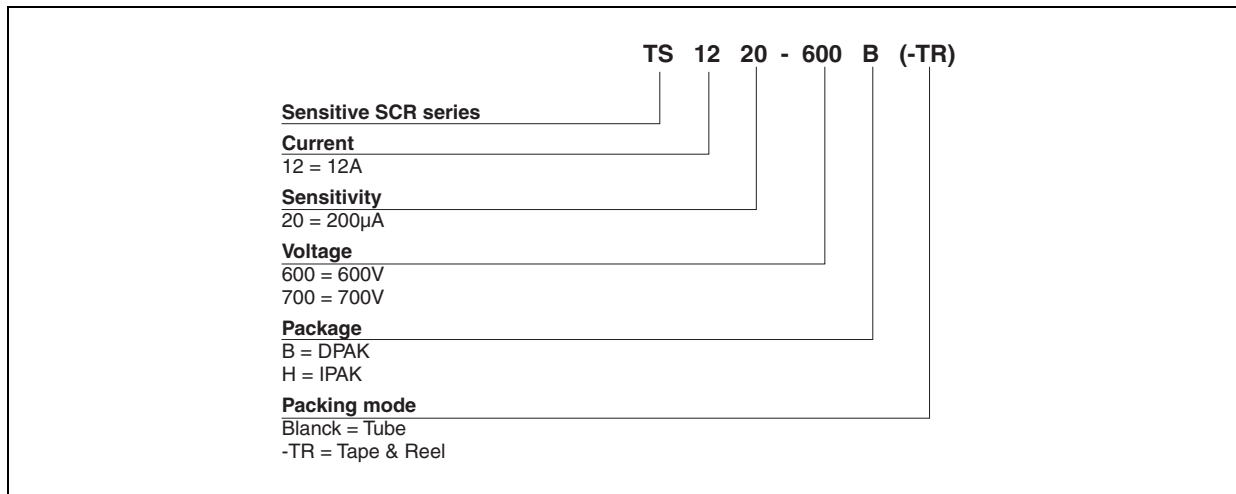


Figure 17: Ordering Information Scheme (TYN08 series)

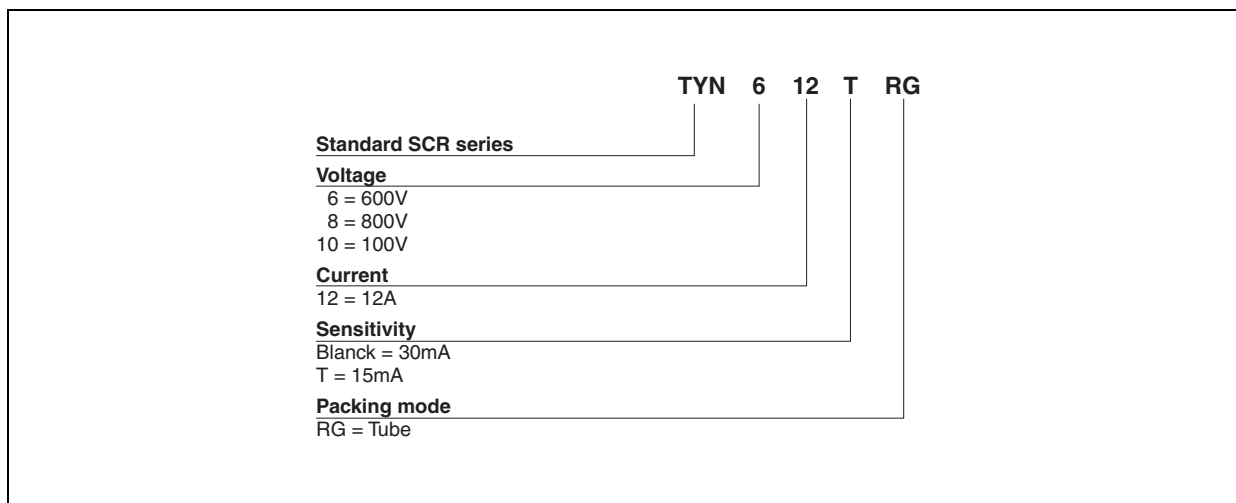


Table 7: Product Selector

Part Numbers	Voltage (xxx)				Sensitivity	Package
	600 V	700 V	800 V	1000 V		
TN1215-xxxB	X		X		15 mA	DPAK
TN1215-xxxG	X		X	X	15 mA	D ² PAK
TN1215-xxxH	X		X		15 mA	IPAK
TS1220-xxxB	X	X			0.2 mA	DPAK
TS1220-xxxH	X	X			0.2 mA	IPAK
TYNx12	X		X	X	15 mA	TO-220AB
TYNx12T	X		X	X	5 mA	TO-220AB

Figure 18: DPAK Package Mechanical Data

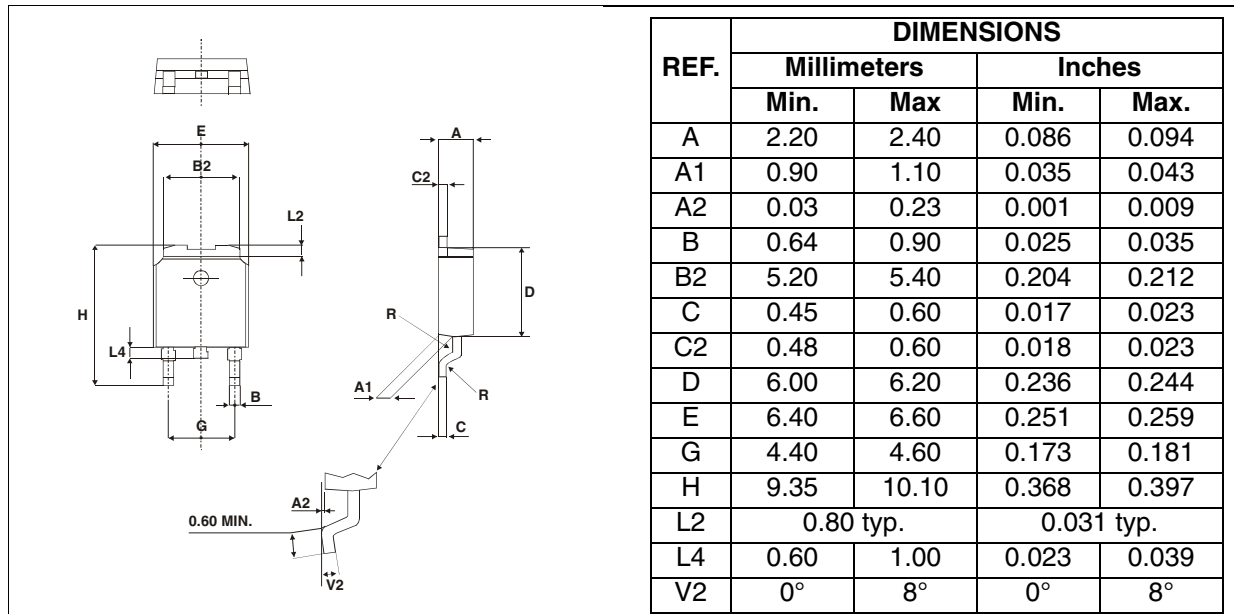


Figure 19: DPAK Foot Print Dimensions (in millimeters)

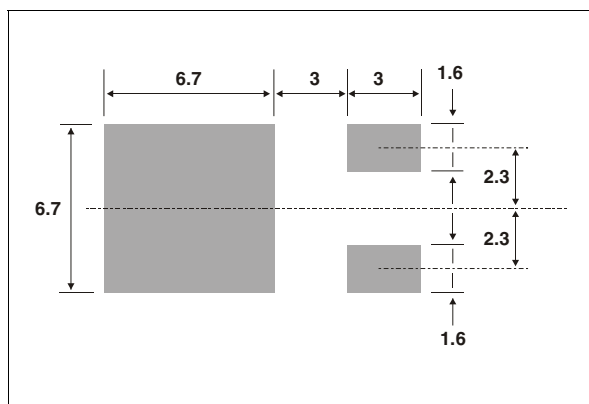


Figure 20: D²PAK Package Mechanical Data

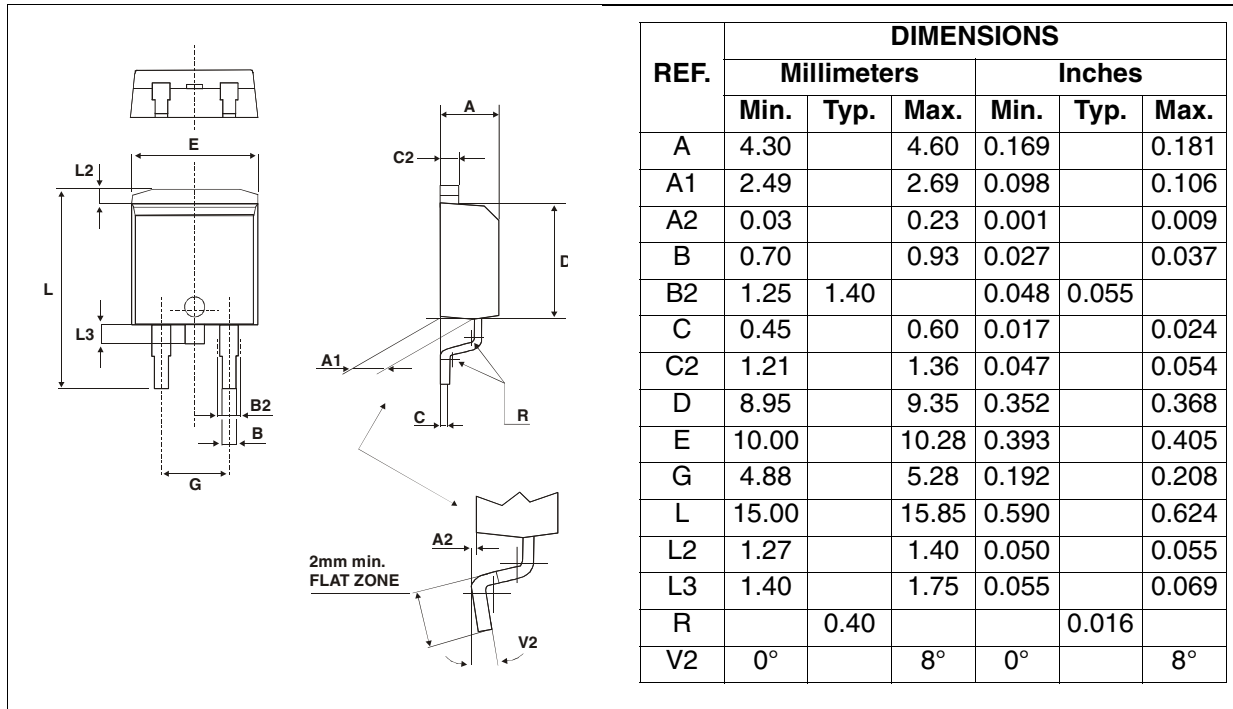


Figure 21: D²PAK Foot Print Dimensions (in millimeters)

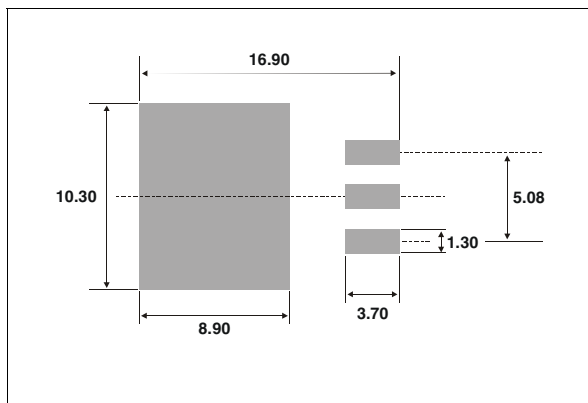


Figure 22: IPAK Package Mechanical Data

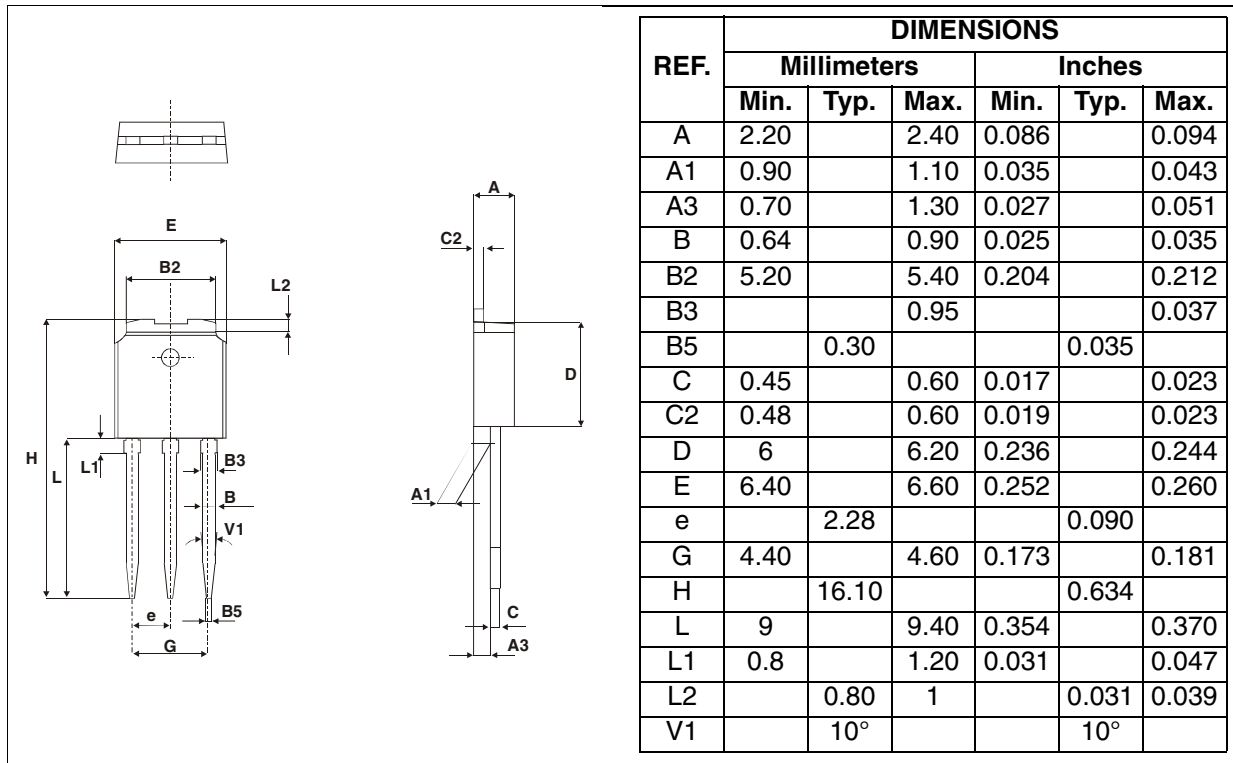
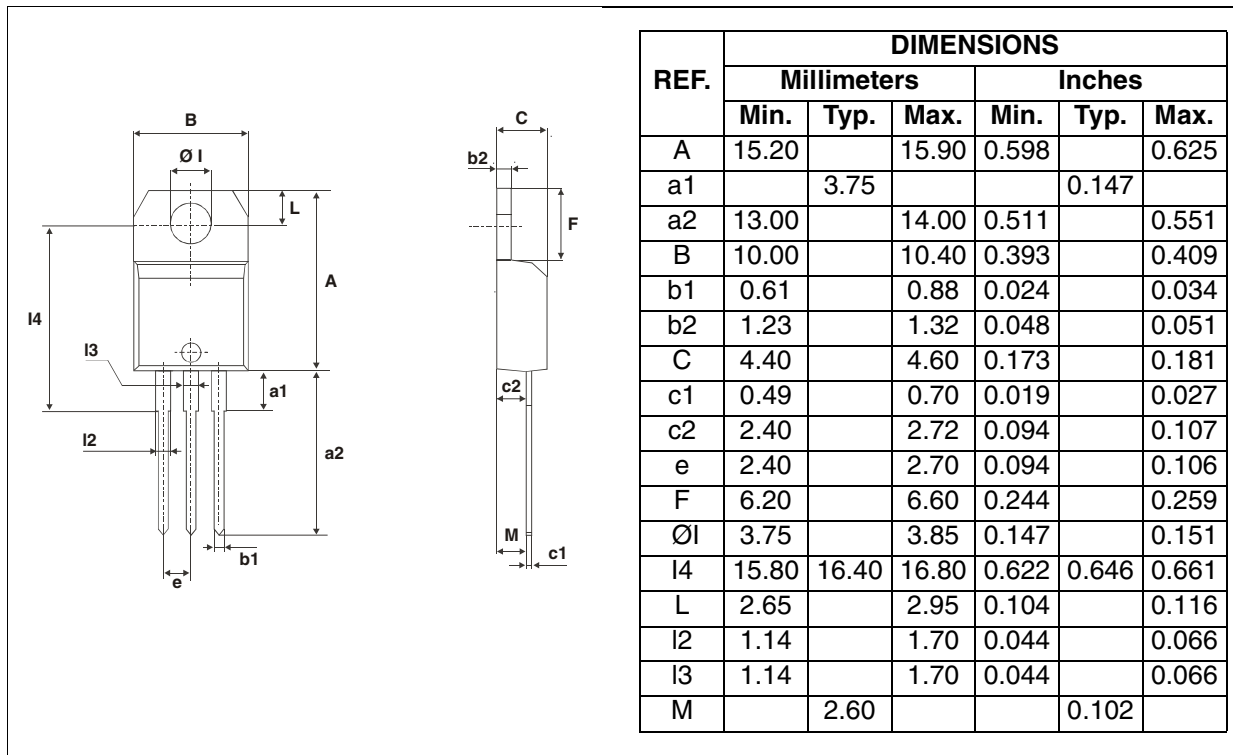


Figure 23: TO-220AB Package Mechanical Data



TN12, TS12 and TYNx12 Series

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect . The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

Table 8: Ordering Information

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
TN1215-x00B	TN1215x00	DPAK	0.3 g	75	Tube
TN1215-x00B-TR	TN1215x00	DPAK	0.3 g	2500	Tape & reel
TN1215-x00G	TN1215x00G	D ² PAK	1.5 g	50	Tube
TN1215-x00G-TR	TN1215x00G	D ² PAK	1.5 g	1000	Tape & reel
TN1215-x00H	TN1215x00	IPAK	0.3 g	75	Tube
TS1220-x00B	TS1220x00	DPAK	0.3 g	75	Tube
TS1220-x00B-TR	TS1220x00	DPAK	0.3 g	2500	Tape & reel
TS1220-x00H	TS1220x00	IPAK	0.3 g	75	Tube
TYNx12RG	TYNx12	TO-220AB	2.3 g	50	Tube
TYNx12TRG	TYNx12T	TO-220AB	2.3 g	50	Tube

Note: x = voltage

Table 9: Revision History

Date	Revision	Description of Changes
Sep-2000	3	Last update.
25-Mar-2005	4	TO-220AB delivery mode changed from bulk to tube.
14-Oct-2005	5	Changed sensitivity values in Table 7 for TYNx12 (30 to 15 mA) and TYNx12T (15 to 5 mA). Added ECOPACK statement

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